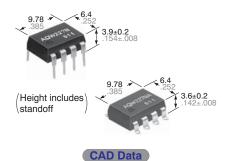
ideas for life

DIP8-pin type featuring low on-resistance with 200V/400V load voltage

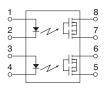
Photo MOS® RF 2 Form A

Low on-resistance (AQW22ON)

Panasonic



mm inch



FEATURES

- 1. 2-channels (Form A) type with high response speed, low leakage current and low on-resistance.
- 2. Applicable for 2 Form A use as well as two independent 1 Form A use
- 3. Low capacitance between output terminals ensures high response speed:

The capacitance between output terminals is small; typ. 10 pF. This enables for a fast operation speed of typ. 0.2 ms.

4. High sensitivity and low onresistance:

Max. 0.07 A of load current can be controlled with input current of 5 mA. The on-resistance is less than our conventional models.

5. Low-level off state leakage current 6. Controls low-level analog signals:

PhotoMOS relay features extremely low closed-circuit offset voltages to enable control of small analog signals without distortion.

TYPICAL APPLICATIONS

Measuring instruments

Scanner, IC checker, Board tester, etc.

TYPES

	Output rating*				Par	Packing quantity			
			Package	Through hole terminal	Surface-mount terminal				
	Load	ad Load	rackage			Tape and reel	l packing style		
	voltage	current		Tube packing style		Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side	Tube	Tape and reel
AC/DC dual use	200 V	50 mA	DIP8-pin	AQW227N	AQW227NA	AQW227NAX	AQW227NAZ	1 tube contains: 50 pcs.	1,000 pcs.
	400 V	40 mA		AQW224N	AQW224NA	AQW224NAX	AQW224NAZ	1 batch contains: 500 pcs.	1,000 pcs.

^{*}Indicate the peak AC and DC values.

Note: The surface mount terminal indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQW227N(A)	AQW224N(A)	Remarks
Input	LED forward current	lF	50 mA		
	LED reverse voltage	VR	5 V		
	Peak forward current	IFP	1 A		f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW		
0.1.1	Load voltage (peak AC)	VL	200 V	400 V	
	Continuous load current	IL	0.05 A (0.07 A)	0.04 A (0.05 A)	Peak AC, DC (): in case of using only 1 channel
Output	Peak load current	Ipeak	0.15 A	0.12 A	A connection: 100 ms (1 shot), V _L = DC
	Power dissipation	Pout	800 mW		
Total power dissipation		Рт	850 mW		
I/O isolation voltage		Viso	1,500 V AC		
Temperature limits	Operating	Торг	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures
	Storage	T _{stg}	-40°C to +100°C −40°F to +212°F		

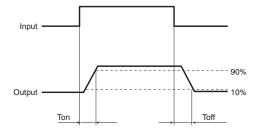
RF 2 Form A Low on-resistance (AQW22ON)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item		Symbol	AQW227N(A)	AQW224N(A)	Remarks
	LED	Typical		0.9 mA		IL = Max.
Input	LED operate current	Maximum	Fon	3.0 mA		
	I ED 4#	Minimum		0.4 mA		IL = Max.
	LED turn off current	Typical	Foff	0.8 mA		
	LED drapaut valtage	Typical	VF	1.25 V (1.14 V at I _F = 5 mA)		I _F = 50 mA
	LED dropout voltage	Maximum	VF	1.5 V		
Output	0	Typical	_	30 Ω	70 Ω	IF = 5 mA $I_{L} = Max.$ Within 1 s on time
	On resistance	Maximum	Ron	50 Ω	100 Ω	
	2	Typical	0	10 pF		I _F = 0 V _B = 0 f = 1 MHz
	Output capacitance	Maximum	Cout	15 pF		
	Off state leakage current	Maximum	Leak	10 nA (1 nA or less)*		I _F = 0 V _L = Max.
	Turn on time*	Typical	Ton	0.2 ms		IF = 5 mA IL = Max.
	Turn on time	Maximum	I on	0.5 ms		
- ,	Turn off time*	Typical	Toff	0.08 ms		I _F = 5 mA I _L = Max.
Transfer characteristics	Turn on time	Maximum	I off	0.2 ms		
	I/O capacitance	Typical	Ciso	0.8 pF		f = 1 MHz V _B = 0
	1/О сараснансе	Maximum	Ciso	1.5 pF		
	Initial I/O isolation resistance	Minimum	Riso	1,000 MΩ		500 V DC

^{*} Available as custom orders (1 nA or less)

^{**}Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	l _F	5	mA

- **Dimensions**
- **Schematic and Wiring Diagrams**
- **■** Cautions for Use
- These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic technical representative.

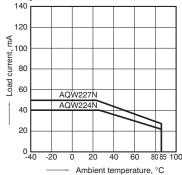
Please refer to our information on PhotoMOS Relays for Automotive Applications.

REFERENCE DATA

Load current vs. ambient temperature characteristics

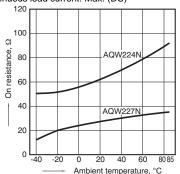
Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

When using 2 channels



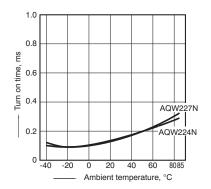
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



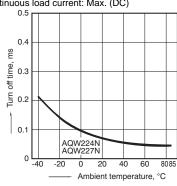
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



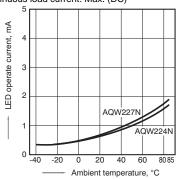
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



5. LED operate current vs. ambient temperature characteristics

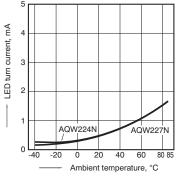
Load voltage: Max. (DC); Continuous load current: Max. (DC)



6. LED turn off current vs. ambient temperature characteristics

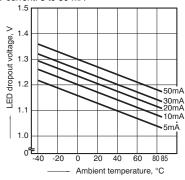
Load voltage: Max. (DC);

Continuous load current: Max. (DC)



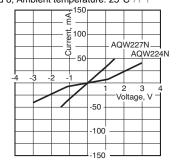
7. LED dropout voltage vs. ambient temperature characteristics

Sample: All types; LED current: 5 to 50 mA



8. Voltage vs. current characteristics of output at MOS portion

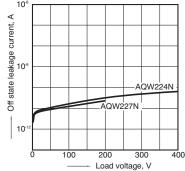
Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



9. Off state leakage current

Measured portion: between terminals 5 and 6,

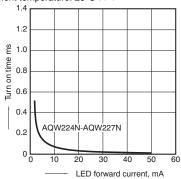
Ambient temperature: 25°C 77°F



RF 2 Form A Low on-resistance (AQW22ON)

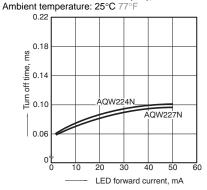
10.LED forward current vs. turn on time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



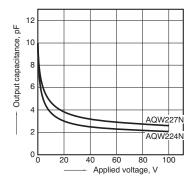
11.LED forward current vs. turn off time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC);



12. Applied voltage vs. output capacitance characteristics

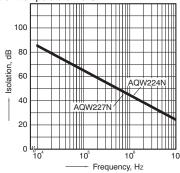
Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz, 30 mVrms; Ambient temperature: 25°C $77^{\circ}F$



13.Isolation characteristics (50 Ω impedance)

Measured portion: between terminals 5 and 6, 7 and 8;

Ambient temperature: 25°C 77°F



14.Insertion loss characteristics

(50 Ω impedance)

Measured portion: between terminals 5 and 6, 7 and 8;

Ambient temperature: 25°C 77°F

